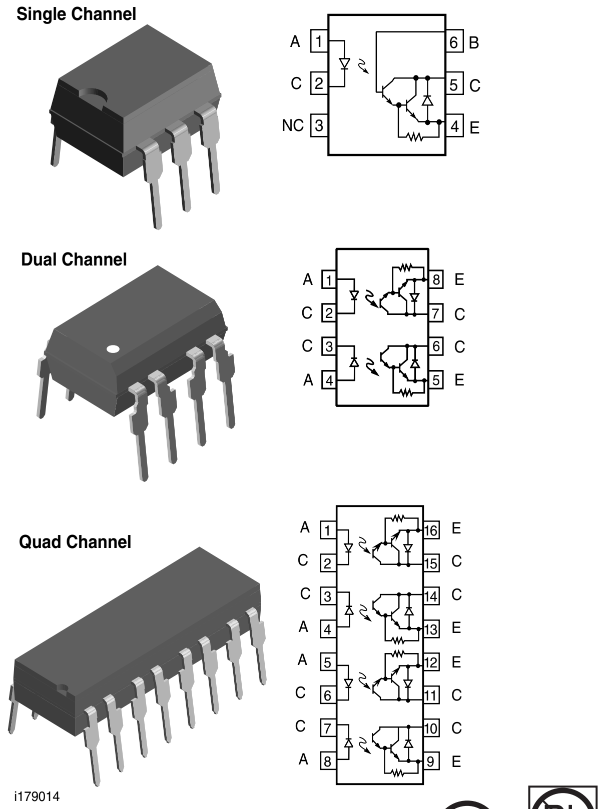
Optocoupler, Photodarlington Output, With Internal Rbe (Single, Dual, Quad Channel)



Features

- Internal RBE for High Stability
- Four Available CTR Categories per Package Type
- BV_{CEO} > 60 V
- Standard DIP Packages
- Lead-free component
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

Agency Approvals

- UL1577, File No. E52744 System Code H or J, Double Protection
- DIN EN 60747-5-2 (VDE0884)
  DIN EN 60747-5-5 pending
  Available with Option 1

Description

IL66, ILD66, and ILQ66 are optically coupled isolators employing Gallium Arsenide infrared emitters and silicon photodarlington detectors. Switching can be accomplished while maintaining a high degree of isolation between driving and load circuits, with no crosstalk between channels.

Order Information

Part	Remarks
IL66-1	CTR ≥ 100 %, DIP-6
IL66-2	CTR ≥ 300 %, DIP-6
IL66-3	CTR ≥ 400 %, DIP-6
IL66-4	CTR ≥ 500 %, DIP-6
ILD66-1	CTR ≥ 100 %, DIP-8
ILD66-2	CTR ≥ 300 %, DIP-8
ILD66-3	CTR ≥ 400 %, DIP-8
ILD66-4	CTR ≥ 500 %, DIP-8
ILQ66-1	CTR ≥ 100 %, DIP-16
ILQ66-2	CTR ≥ 300 %, DIP-16
ILQ66-3	CTR ≥ 400 %, DIP-16
ILQ66-4	CTR ≥ 500 %, DIP-16
IL66-4X009	CTR ≥ 500 %, SMD-8 (option 9)
ILD66-2X007	CTR ≥ 300 %, SMD-8 (option 7)
ILD66-3X009	CTR ≥ 400 %, SMD-8 (option 9)
ILD66-4X009	CTR ≥ 500 %, SMD-8 (option 9)
ILQ66-4X007	CTR ≥ 500 %, SMD-16 (option 7)
ILQ66-4X009	CTR ≥ 500 %, SMD-16 (option 9)

For additional information on the available options refer to Option Information.

Absolute Maximum Ratings

T_{amb} = 25 °C, unless otherwise specified

Stresses in excess of the absolute Maximum Ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute Maximum Rating for extended periods of the time can adversely affect reliability.

Input

Each Channel

Parameter	Test condition	Symbol	Value	Unit
Peak reverse voltage		V_{RM}	6.0	V
Forward continuous current		I_F	60	mA
Power dissipation		P_{diss}	100	mW
Derate linearly from 25 °C			1.33	mW/°C

Output

Parameter	Test condition	Symbol	Value	Unit
Power dissipation		P_{diss}	150	mW
Derate linearly from 25°C			2.0	mW/°C

Coupler

Parameter	Test condition	Part	Symbol	Value	Unit
Isolation test voltage	t = 1.0 sec.		V_{ISO}	5300	V_{RMS}
Total package power dissipation		IL66	P_{tot}	250	mW
		ILD66	P_{tot}	400	mW
		ILQ66	P_{tot}	500	mW
Derate linearly from 25 °C		IL66		3.3	mW/°C
		ILD66		5.33	mW/°C
		ILQ66		6.67	mW/°C
Creepage				≥ 7.0	min
Clearance				≥ 7.0	min
Comparative tracking index				175	
Isolation resistance	V_{IO} = 500 V, T_{amb} = 25 °C		R_{IO}	$\geq 10^{12}$	Ω
	V_{IO} = 500 V, T_{amb} = 100 °C		R_{IO}	$\geq 10^{11}$	Ω
Storage temperature			T_{stg}	- 55 to + 125	°C
Operating temperature			T_{amb}	- 55 to + 100	°C
Lead soldering time at 260 °C				10	sec.

Electrical Characteristics

T_{amb} = 25 °C, unless otherwise specified
Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.

Input

GaAs Emitter

Parameter	Test condition	Symbol	Min	Typ.	Max	Unit
Forward voltage	I_F = 20 mA	V_F		1.25	1.5	V
Reverse current	V_R = 6.0 V	I_R		0.1	10	μA
Capacitance	V_R = 0 V	C_O		25		pF

Output

Parameter	Test condition	Symbol	Min	Typ.	Max	Unit
Collector-emitter breakdown voltage	I_C = 1.0 mA, I_F = 0	BV_{CEO}	60			V
Collector-base breakdown voltage (IL66)	I_C = 10 μA	BV_{CBO}	60			V
Collector-emitter leakage current	V_{CE} = 50 V, I_F = 0	I_{CEO}		1.0	100	nA
Capacitance, collector-emitter	V_{CE} = 10 V			3.4		pF

Coupler

Parameter	Test condition	Symbol	Min	Typ.	Max	Unit
Saturation voltage, collector-emitter	I_C = 10 mA, I_F = 10 mA	V_{CEsat}		0.9	1.0	V

Current Transfer Ratio

Parameter	Test condition	Part	Symbol	Min	Typ.	Max	Unit
Current Transfer Ratio	I_F = 2.0 mA, V_{CE} = 10 V	IL(D,Q)66-1	CTR	100	400		%
		IL(D,Q)66-2	CTR	300	500		%
	I_F = 0.7 mA, V_{CE} = 10 V	IL(D,Q)66-3	CTR	400	500		%
	I_F = 2.0 mA, V_{CE} = 5.0 V	IL(D,Q)66-4	CTR	500	750		%

Switching Characteristics

Parameter	Test condition	Symbol	Min	Typ.	Max	Unit
Rise time -1, -2, -4	V_{CC} = 10 V	t_r			200	µs
Fall time -1, -2, -4	I_F = 2.0 mA, R_L = 100 Ω	t_f			200	µs
Rise time -3	I_F = 0.7 mA	t_r			200	µs
Fall time -3	V_{CC} = 10 V, R_L = 100 Ω	t_f			200	µs

Typical Characteristics (Tamb = 25 °C unless otherwise specified)

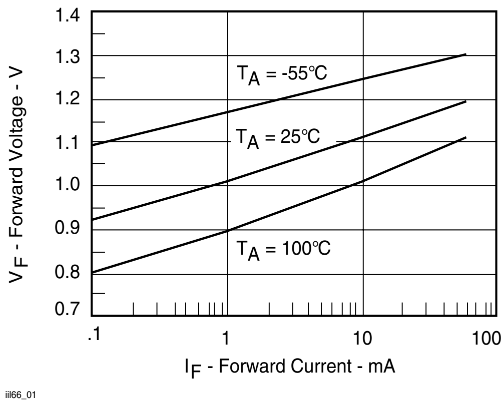


Figure 1. Forward Voltage vs. Forward Current

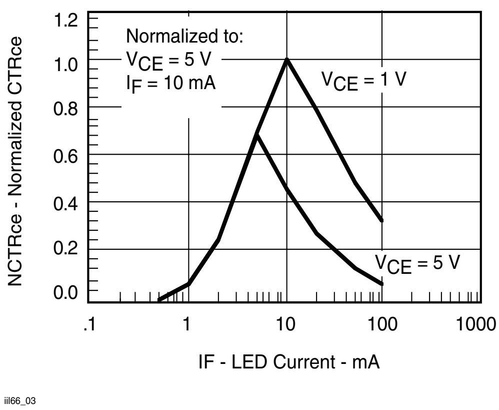


Figure 3. Normalized Non-saturated and Saturated CTR_{CE} vs. LED Current

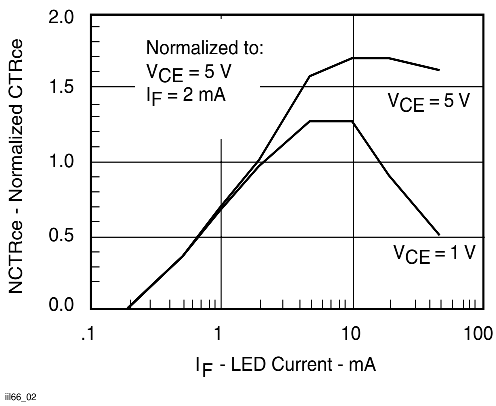


Figure 2. Normalized Non-saturated and Saturated CTR_{CE} vs. LED Current

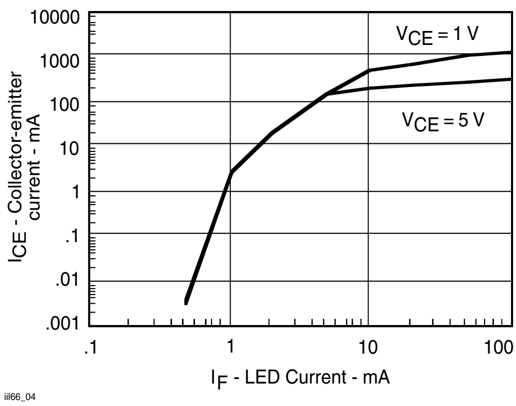


Figure 4. Non-Saturated and Saturated Collector Emitter Current vs. LED Current

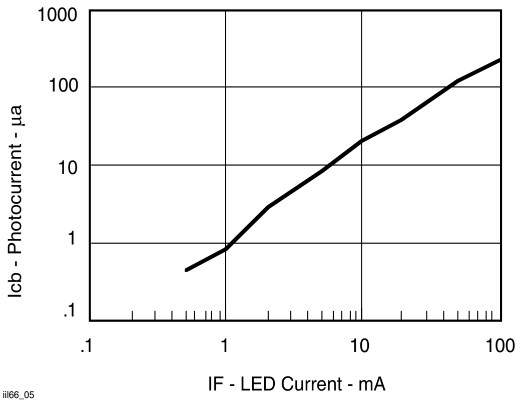


Figure 5. Collector-Base Photocurrent vs. LED Current

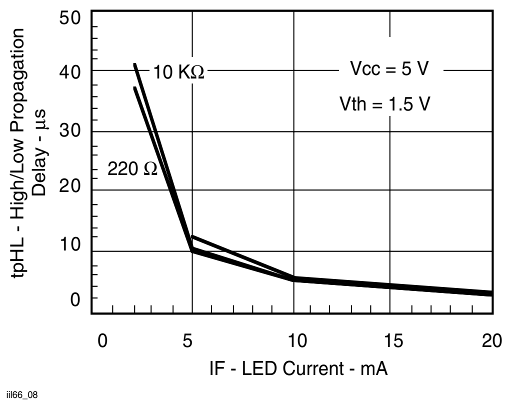


Figure 8. High to low Propagation Delay vs. Collector Load Resistance and LED Current

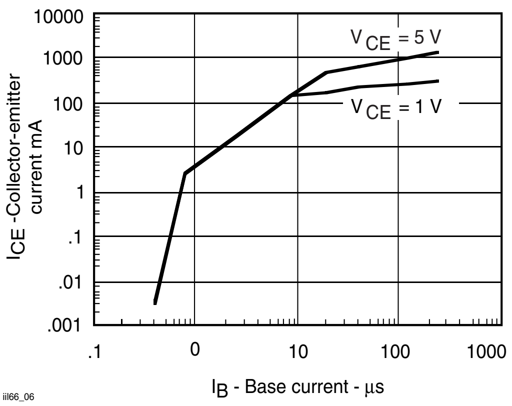


Figure 6. Collector-Emitter Current vs.LED Current

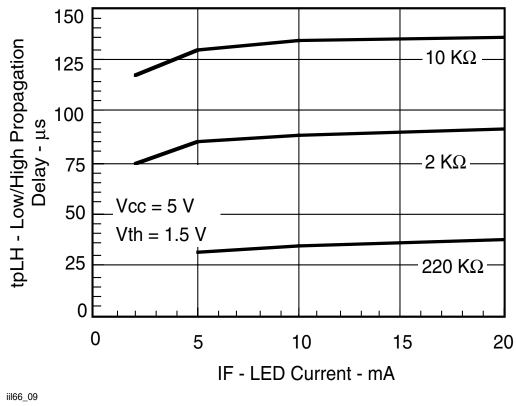


Figure 9. Low to High Propagation Delay vs. Collector Load Resistance and LED Current

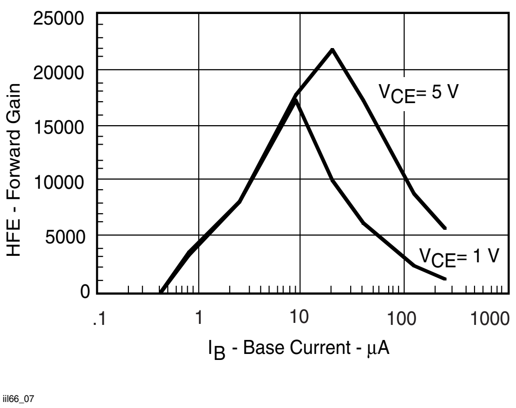


Figure 7. Non-Saturated and Saturated HFE vs. LED Current

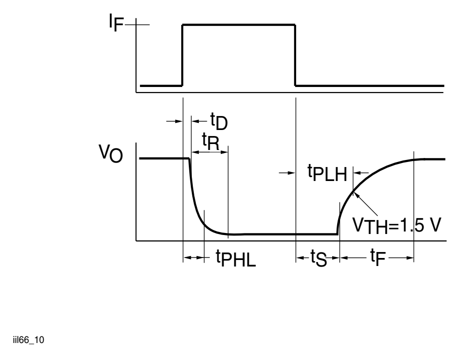
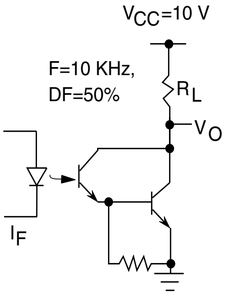


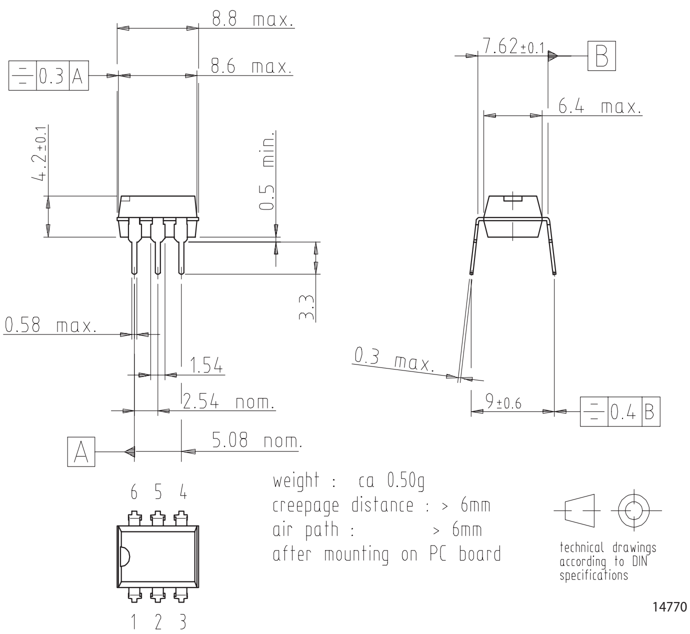
Figure 10. Switching Waveform

Figure 11. Switching Schematic

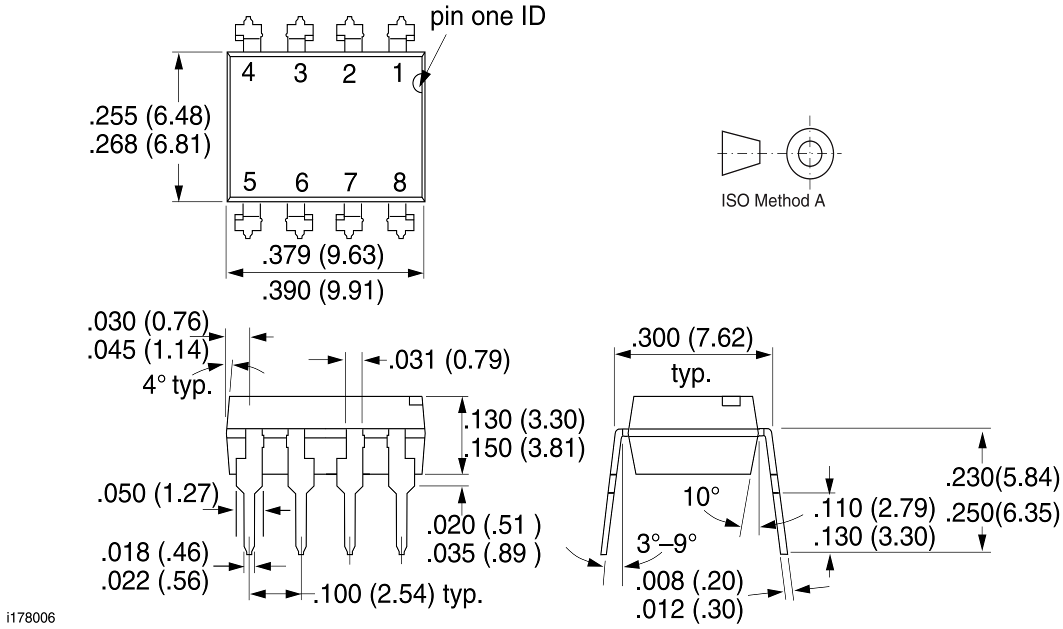


iil66_11

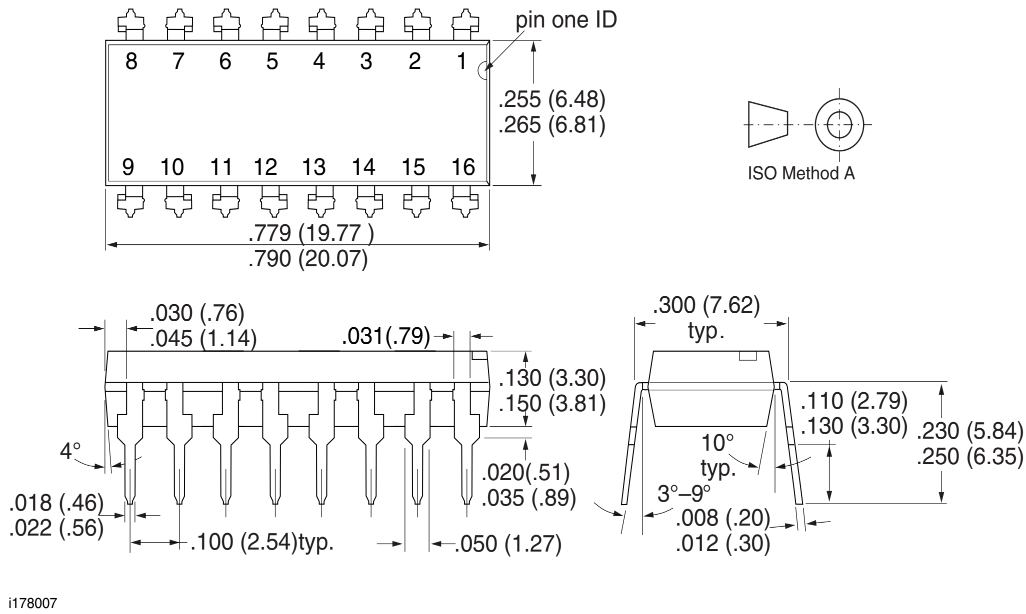
Package Dimensions in mm



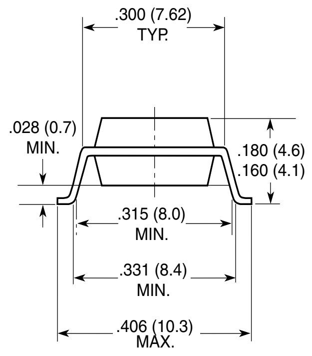
Package Dimensions in Inches (mm)



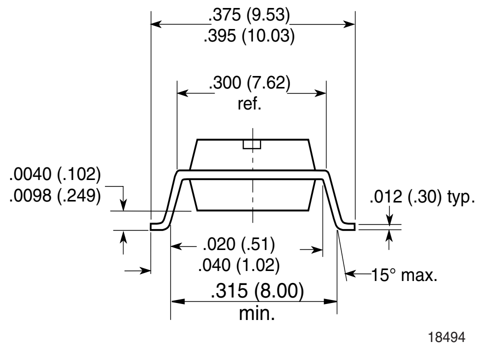
Package Dimensions in Inches (mm)



Option 7



Option 9



Ozone Depleting Substances Policy Statement

It is the policy of Vishay Semiconductor GmbH to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operatingsystems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

Vishay Semiconductor GmbH, P.O.B. 3535, D-74025 Heilbronn, Germany
Telephone: 49 (0)7131 67 2831, Fax number: 49 (0)7131 67 2423

Notice

Specifications of the products displayed herein are subject to change without notice. Vishay Intertechnology, Inc., or anyone on its behalf, assumes no responsibility or liability for any errors or inaccuracies.

Information contained herein is intended to provide a product description only. No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document. Except as provided in Vishay's terms and conditions of sale for such products, Vishay assumes no liability whatsoever, and disclaims any express or implied warranty, relating to sale and/or use of Vishay products including liability or warranties relating to fitness for a particular purpose, merchantability, or infringement of any patent, copyright, or other intellectual property right.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications. Customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Vishay for any damages resulting from such improper use or sale.